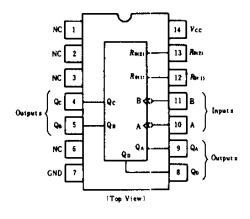
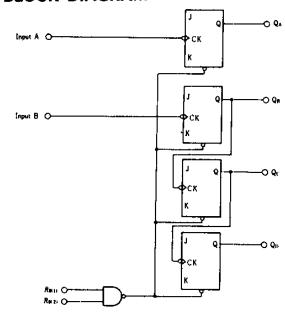
This counter contains four master-slave flip-flops and additional gating to provide a divide-by-two counter and divide-byeight counter. This counter has a gated zero reset. To use the maximum count length of this counter, the B input is connected to the  $Q_{\mathbf{A}}$  output. The input count pulses are applied to input A and the outputs are as described in the appropriate function table.

### **■ PIN ARRANGEMENT**



### **■BLOCK DIAGRAM**



### **MABSOLUTE MAXIMUM RATINGS**

Item		Symbol	Ratings	Unit
Supply voltage		Vcc	7.0	v
Input voltage	Ro Inputs	1,	7.0	V
	A, B Inputs	V <sub>IN</sub>	5.5	V
Operating temperature range		T.,,	-20~+75	·c
Storage temperature range		Tete	-65~+150	<b>°</b> C

### **FUNCTION TABLE**

### Reset/Count

Reset	Input		puts				
Ro (1)	Roger	Q□	Q۵	Qa	Q		
Н	Н	L	L.	L	L		
L	×	Count					
×	L	Count					

### BCD Count Sequence

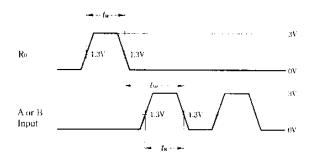
_		Out	puts		C		Out	puts	
Count	Qn	Qc	Q <sub>B</sub>	Q۸	Count	Q₀	Qc	Qв	Q۸
0	L	L	L	L	8	Н	L	L	L
1	L	L	L	н	9	Н	L	L	Н
2	L	L	Н	L	10	Н	L	H	L
3	L	L	н	н	11	Н	L	Н	Н
4	L	Н	L	L	12	Н	Н	L	L
5	L	Н	L	Н	13	Н	Н	L	Н
6	L	Н	Н	L	14	Н	Н	н	L
7	L	Н	Н	н	15	н	Н	Н	Н

Notes) 1. H; high level, L; low level, X; irrelevant.
2. Output Q<sub>A</sub> is connected to input B.

### **M**RECOMMENDED OPERATING CONDITIONS

Item		Symbol	min	typ	max	Unit	
Output curre	ent	Іон		_ "	-400	$\mu$ A	
Output current		IoL	_	_   -		m.A	
Count	A input		0	_	32	MHz	
frequency	B input	fcount	0		16	IVIT1 2	
	A input	t w	15	-	_		
Pulse width	B input		30	_	-	ns	
1 dise width	Reset inputs		15	_	_	115	
Setup time		t.,	25			ns	

### **TIMING DEFINITION**



## **MELECTRICAL CHARACTERISTICS** ( $Ta = -20 \sim +75$ °C)

lte	m	Symbol	Test Conditions		min	typ•	max	Unit
Input voltage		Vin			2.0	_	_	V
Input voltage		$V_{IL}$			_		0.8	V
		$V_{OH}$	$V_{CC} = 4.75 \text{V}, V_{IH} = 2 \text{V}, V_{IL} = 0.8 \text{V},$	<i>I<sub>OH</sub></i> = − 400 μA	2.7		_	V
Output voltage		<b>V</b> 01.	$V_{CC} = 4.75 \text{V}, V_{DI} = 2 \text{V}, V_{DI} = 0.8 \text{V}$	$I_{OL} = 4 \mathrm{mA}^{**}$	_		0.4	v
		Vol.	$V_{CC} = 4.75 \text{ V},  V_{IR} = 2 \text{ V},  V_{IL} = 0.8 \text{ V}$ $I_{OL} = 8 \text{ mA}^*$		_		0.5	V
	Any Reset				_		0.4	
	A input	$I_{tt}$	$V_{CC} = 5.25 \text{V}, V_I = 0.4 \text{V}$				-2.4	mА
B input	B input					1.6		
	Any Reset	1			_		20	
Input current	A input	$I_{IH}$	$V_{CC} = 5.25 \text{ V},  V_i = 2.7 \text{ V}$		_	_	40	μA
	B input				_	_	40	
	Any Reset			$V_I = 7 \text{ V}$			0.1	
A input	A input	$I_t$	Vcc = 5.25 V	77 6 537			0.2	mA
B input				$V_{\ell}=5.5V$	_		0.2	
Short-circuit ou	tput current	Ios	$V_{CC} = 5.25 \text{V}$		20		100	mΑ
Supply current*	•	$I_{cc}$	Vcc - 5.25V	1	_	9	15	mA
Input clamp volt	age	$V_{tK}$	$V_{CC} = 4.75 \text{V}, I_{IN} = -18 \text{mA}$		_		-1.5	V

<sup>\*</sup>  $V_{CC}$ =5V, Ta=25°C

# **ESWITCHING CHARACTERISTICS** ( $V_{cc} = 5V$ , $T_a = 25^{\circ}C$ )

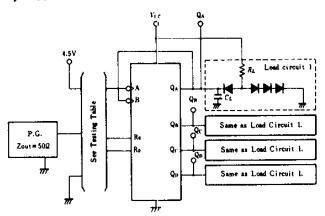
Item	Symbol	Inputs	Outputs	Test Conditions	min	typ	max	Unit			
Manimum and formal and		Α	Q <sub>A</sub>		32	42	_	2411			
Maximum count frequency	fmaz	В	Qв		16	_		MHz			
	t PLH	Α				10	16				
	t PHL	A	A Q.			12	18	ns			
	tpln								46	70	
	t PH L	A	Q <sub>0</sub>	$C_L = 15 \mathrm{pF}, \ R_L = 2 \mathrm{k}\Omega$		46	70	ns			
	t PLH	D	0		_	10	16	ns			
Propagation delay time	l PHL	В	Qв		_	14	21				
	t PLH	ъ				21	32				
	t PHL	В	Qc			23	35				
	t PLH	D.			_	34	51				
	t PHL	В	Q₽		_	34	51	ns			
	t <sub>PHL</sub>	Set-to-0	$Q_A \sim Q_D$			26	40	ns			

<sup>\*\*</sup>  $Q_A$  output is tested at specified  $I_{OL}$  plus the limit value of  $I_{IL}$  for the B input. This permits driving the B input while maintaining full fan-out capability.

<sup>\*\*\*</sup> I<sub>CC</sub> is measured with all outputs open, both R<sub>0</sub> inputs grounded following momentary connection to 4.5V, and all other inputs grounded.

### TESTING METHOD

### 1) Test Circuit



Notes) 1.  $C_L$  includes probe and jig capacitance.

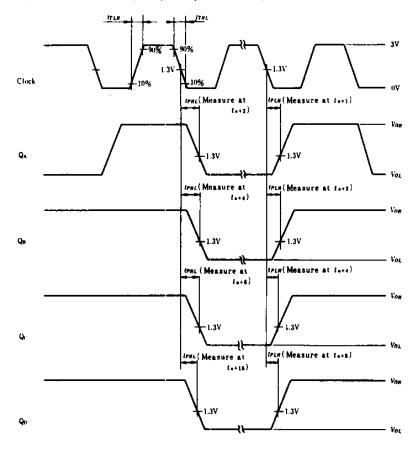
2. All diodes are 1S2074 (B).

### 2) Testing Table

From inp		Inputs			Outputs				
Item	to output	A	В	R₀	Q۸	Qв	Qc	Qo	
	A→Q	IN	to QA	GND	OUT	OUT	OUT	OUT	
f=az	B→Q	4.5V	IN	GND		OUT	OUT	OUT	
	A→Q <sub>A</sub>	IN	to QA	GND	OUT		-		
	$A \rightarrow Q_D$	IN	to QA	GND		<u> </u>		OUI	
t <sub>PLH</sub>	B→Q <sub>8</sub>	4.5V	IN	GND	_	OUT	-	_	
t PHL	B→Qc	4.5V	IN	GND	_		OUT	_	
	B→Q₀	4.5V	IN	GND			_	OUT	
	R <sub>0</sub> →Q**	IN*	to QA	IN	OUT	OUT	OUT	ดบา	

<sup>\*</sup> For initialized.

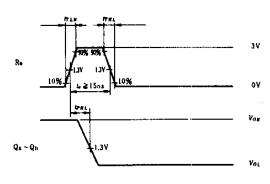
### Waveform 1. f max, t plu, t phi (Clock→Q)



Notes) 1. Input pulse:  $t_{TLH} \le 15$ ns,  $t_{THL} \le 5$ ns, PRR=1 MHz, duty cycle=50% and: for  $f_{max}$ ,  $t_{TLH} = t_{THL} \le 2.5$ ns.

2.  $t_n$  is reference bit time when all outputs are low.

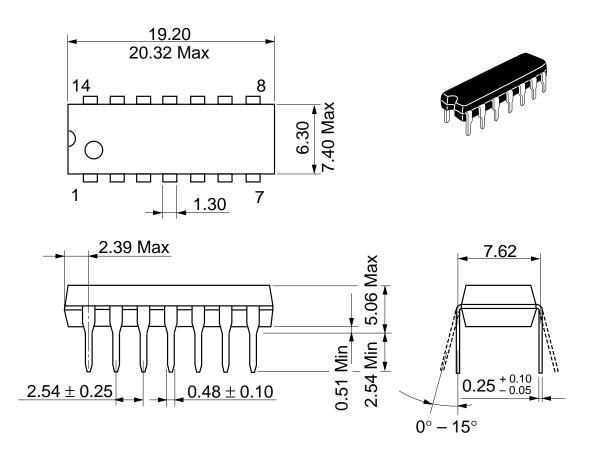
### Waveform 2. trik (Ro→ Q)



Note)  $t_{TLH} \le 15 \text{ ns}, t_{THL} \le 5 \text{ ns}$ 

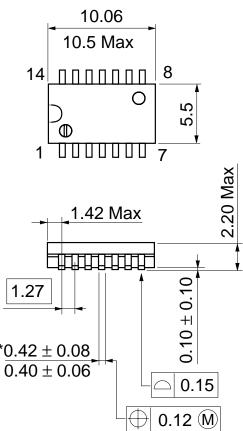
<sup>\*\*</sup> Measured with each input and unused inputs at 4.5V.

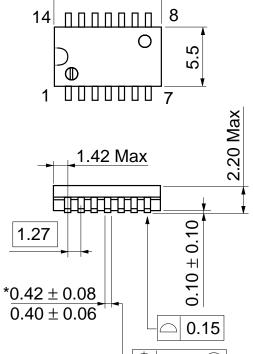
Unit: mm



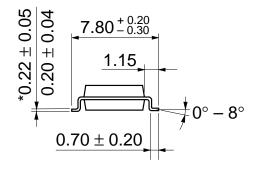
Hitachi Code	DP-14
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.97 g

Unit: mm





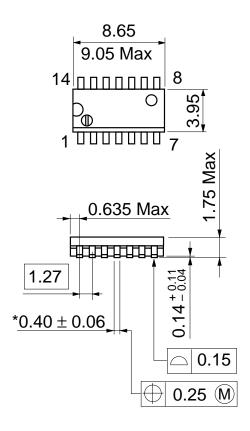




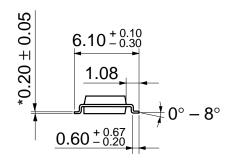
Hitachi Code	FP-14DA
JEDEC	
EIAJ	Conforms
Weight (reference value)	0.23 g

Dimension	including	the	plating	thickness
Bas	se materia	al dir	mensio	1

Unit: mm







Hitachi Coo	de	FP-14DN	
JEDEC		Conforms	
EIAJ		Conforms	
Weight (refe	erence value)	0.13 g	

\*Pd plating

### **Cautions**

- 1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
- 2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
- 3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
- 4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as failsafes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
- 5. This product is not designed to be radiation resistant.
- 6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
- 7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

# HITACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits.

Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

**URL** NorthAmerica http:semiconductor.hitachi.com/ Europe

http://www.hitachi-eu.com/hel/ecg http://www.has.hitachi.com.sg/grp3/sicd/index.htm http://www.hitachi.com.tw/E/Product/SICD\_Frame.htm Asia (Singapore) Asia (Taiwan) Asia (HongKong) http://www.hitachi.com.hk/eng/bo/grp3/index.htm

http://www.hitachi.co.jp/Sicd/indx.htm Japan

#### For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose,CA 95134 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223 Hitachi Europe GmbH Electronic components Group Dornacher Stra§e 3 D-85622 Feldkirchen, Munich Germany

Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd. Electronic Components Group Whitebrook Park Lower Cookham Road Maidenhead

Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 049318 Tel: 535-2100 Fax: 535-1533

Hitachi Asia Ltd. Taipei Branch Office

3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666 Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218 Fax: <852> (2) 730 0281

Telex: 40815 HITEC HX

Copyright 'Hitachi, Ltd., 1999. All rights reserved. Printed in Japan.